 SEMI
CONDUCTOR

### 40V N-Channel Enhancement Mode MOSFET

Current

4.3A

#### Features

Voltage

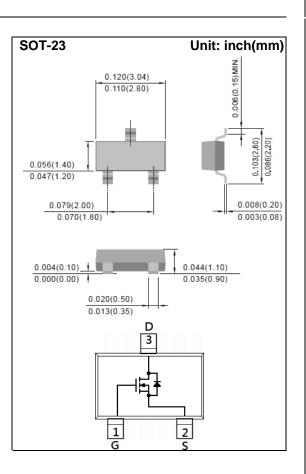
• RDS(ON), VGS@10V, ID@4.3A<42mΩ

40 V

- Rds(ON) , Vgs@4.5V, Id@3.9A<51mΩ
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A40



### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	40	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	4.3	А
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	17.2	А
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W

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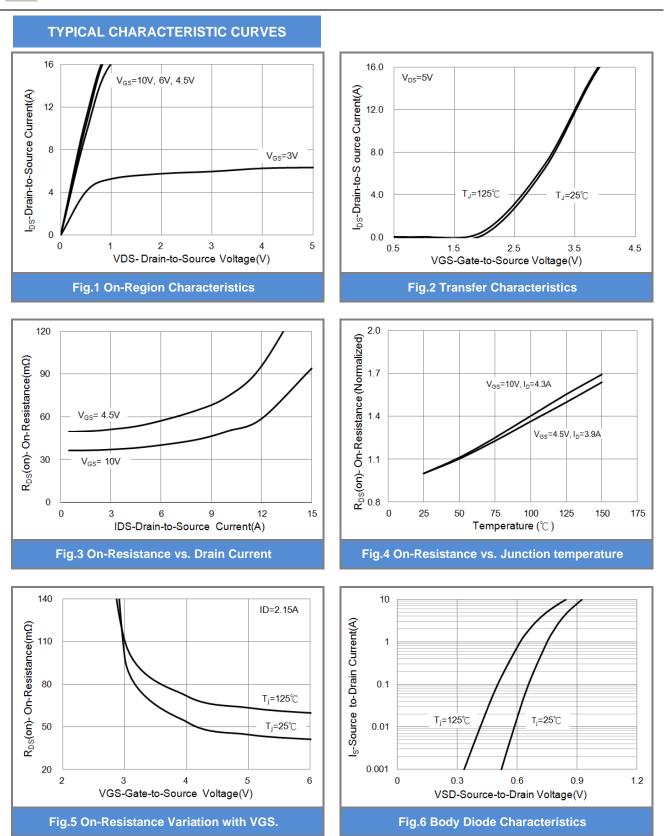
## **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		1				1
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}$ =0V, $I_{D}$ =250uA	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_{D}=250uA$	1.0	1.5	2.5	V
Drain-Source On-State Resistance	5	V <sub>GS</sub> =10V, I <sub>D</sub> =4.3A	-	35	42	mΩ
	$R_{DS(on)}$	V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.9A	-	44	51	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	0.01	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	$Q_{g}$	V <sub>DS</sub> =20V, I <sub>D</sub> =4.3A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	4.8	-	
Gate-Source Charge	$Q_gs$		-	1.4	-	nC
Gate-Drain Charge	$Q_gd$		-	1.8	-	
Input Capacitance	Ciss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	410	-	pF
Output Capacitance	Coss		-	50	-	
Reverse Transfer Capacitance	Crss		-	30	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	4	-	ns
Turn-On Rise Time	tr	$V_{DD}=20V, I_{D}=3.5A,$ $V_{GS}=10V,$ $R_{G}=1\Omega^{(Note 1,2)}$	-	30	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	15	-	
Turn-Off Fall Time	tf	$R_{G}=1\Omega$	-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.0	•
Diode Forward Current	I <sub>S</sub>		-	-	1.0	A
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.78	1.2	V
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =3.5A	-	10.2	-	ns
Reverse Recovery Charge	Qrr	dI <sub>F</sub> / dt=100A/us	-	5.5	-	nC

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





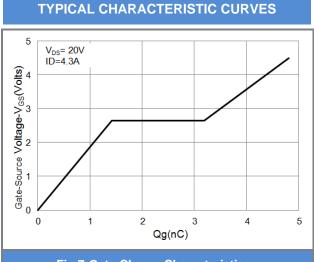


Fig.7 Gate-Charge Characteristics

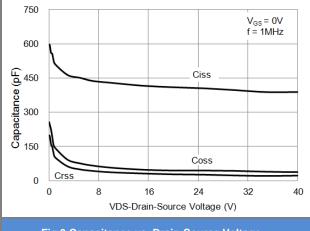
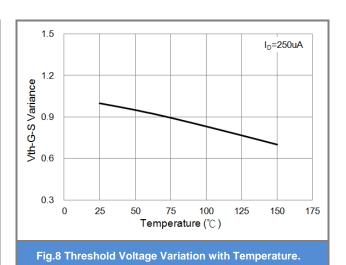


Fig.9 Capacitance vs. Drain-Source Voltage.



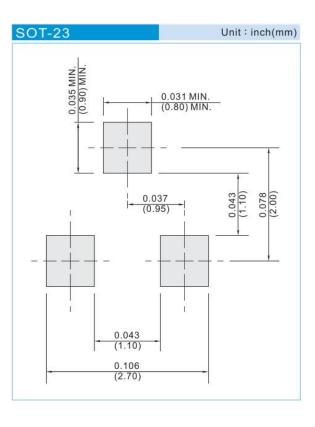




### PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJA3440_R1_00001	SOT-23	3K pcs / 7" reel	A40	Halogen free
PJA3440_R2_00001	SOT-23	12K pcs / 13" reel	A40	Halogen free

### MOUNTING PAD LAYOUT







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